

SG - 2BC

The SG - 2BC reflective sensor combines a GaAs IRED with a high - sensitivity phototransistor in a super - mini (4) ceramic package, reducing installation space.

FEATURES

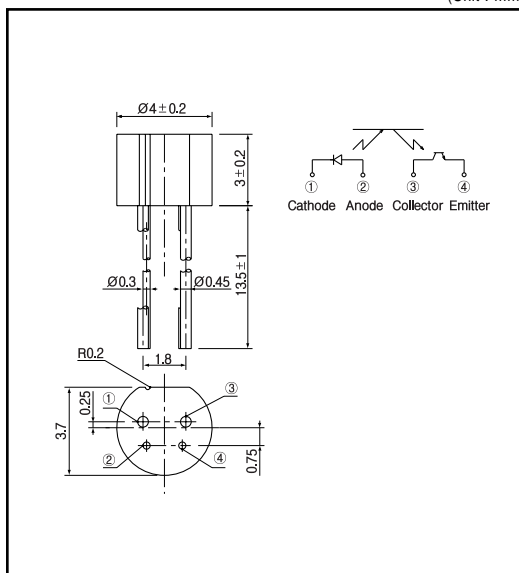
- Compact (ø4mm)
- High performance
- High - speed response
- Easy to mount on P.C.B.
- Widely applicable

APPLICATIONS

- Timing sensors
- Edge sensors
- Micro floppy disk drives
- Level sensors of liquid

DIMENSIONS

(Unit : mm)



MAXIMUM RATINGS

(Ta=25)

	Item	Symbol	Rating	Unit
Input	Power dissipation	P _D	75	mW
	Reverse voltage	V _R	5	V
	Forward current	I _F	50	mA
	Pulse forward current *1	I _{FP}	1	A
Output	Collector power dissipation	P _C	75	mW
	Collector current	I _C	20	mA
	C - E voltage	V _{CE0}	30	V
	E - C voltage	V _{E0}	3	V
	Operating temp.	T _{opr.}	- 20 +90	
	Storage temp.	T _{stg.}	- 30 +100	
	Soldering temp.	T _{sol.}	260	

*1. t w 100 μsec.period :T=10msec.

*2. For MAX. 5 seconds at the position of 2mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

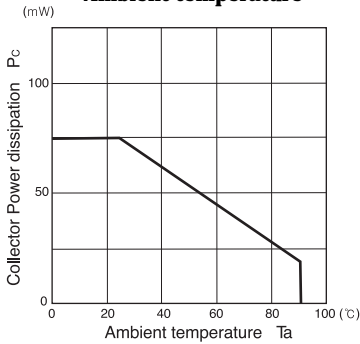
(Ta=25)

	Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Input	Forward voltage	V _F	I _F = 4mA			1.2	V
	Reverse current	I _R	V _R = 5V			10	μA
	Capacitance	C _t	V = 0V, f = 1KHz		25		pF
	Peak wavelength	λ			940		nm
Output	Collector dark current	I _{CEO}	V _{CE} = 10V			0.1	μA
	Ligh current	I _L	V _{CE} = 2V, I _F = 4mA		100		μA
	Leakage current	I _{CEO0}	V _{CE} = 2V, I _F = 4mA			0.1	μA
Switching speeds	Rise time	t _r	V _{CC} = 2V, I _F = 100μA, R = 1k		30		μsec.
	Fall time	t _f			30		μsec.

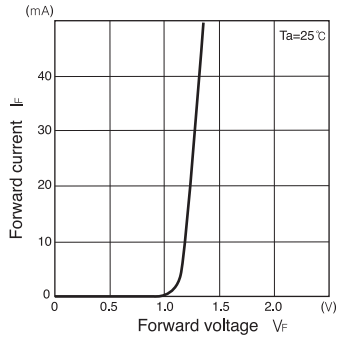
Photo interrupters(Reflective)

SG - 2BC

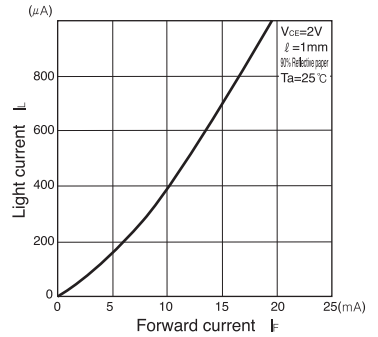
Collector power dissipation Vs. Ambient temperature



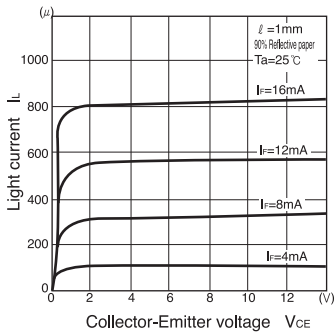
Forward current Vs. Forward voltage



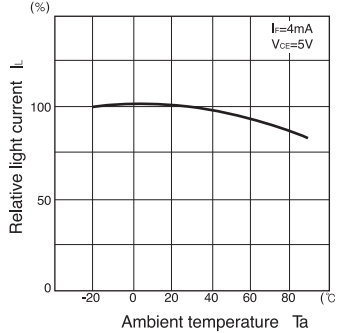
Light current Vs. Forward current



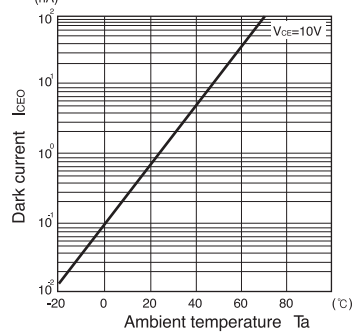
Light current Vs. Collector-Emitter voltage



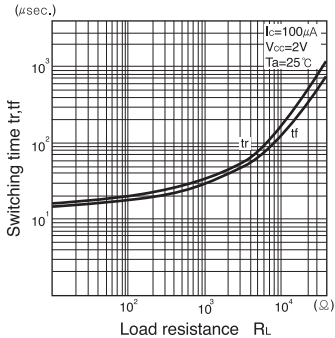
Relative light current Vs. Ambient temperature



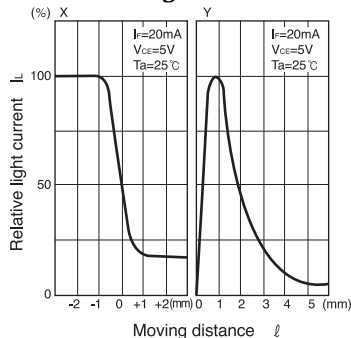
Dark current Vs. Ambient temperature



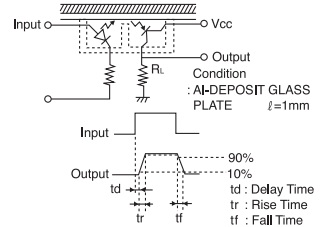
Switching time Vs. Load resistance



Relative light current Vs. Moving distance



Switching time measurement circuit



Method of measuring position characteristic

